

TOSHIBA Field Effect Transistor Silicon P Channel MOS Type (U-MOS III)

# SSM6J50TU

## ○ High Current Switching Applications

- Compact package suitable for high-density mounting
- Low on-resistance:
  - $R_{on} = 205m\Omega$  (max) (@ $V_{GS} = -2.0$  V)
  - $R_{on} = 100m\Omega$  (max) (@ $V_{GS} = -2.5$  V)
  - $R_{on} = 64m\Omega$  (max) (@ $V_{GS} = -4.5$  V)

## Absolute Maximum Ratings (Ta = 25°C)

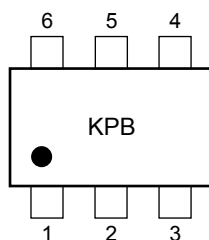
| Characteristics           |       | Symbol            | Rating     | Unit |
|---------------------------|-------|-------------------|------------|------|
| Drain-Source voltage      |       | $V_{DS}$          | -20        | V    |
| Gate-Source voltage       |       | $V_{GSS}$         | $\pm 10$   | V    |
| Drain current             | DC    | $I_D$             | -2.5       | A    |
|                           | Pulse | $I_{DP}$          | -5         |      |
| Drain power dissipation   |       | $P_D$<br>(Note 1) | 500        | mW   |
| Channel temperature       |       | $T_{ch}$          | 150        | °C   |
| Storage temperature range |       | $T_{stg}$         | -55 to 150 | °C   |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

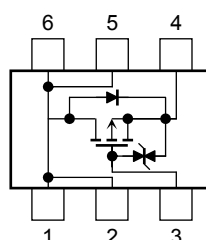
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: Mounted on FR4 board.  
(25.4 mm × 25.4 mm × 1.6 t, Cu Pad: 645 mm<sup>2</sup>)

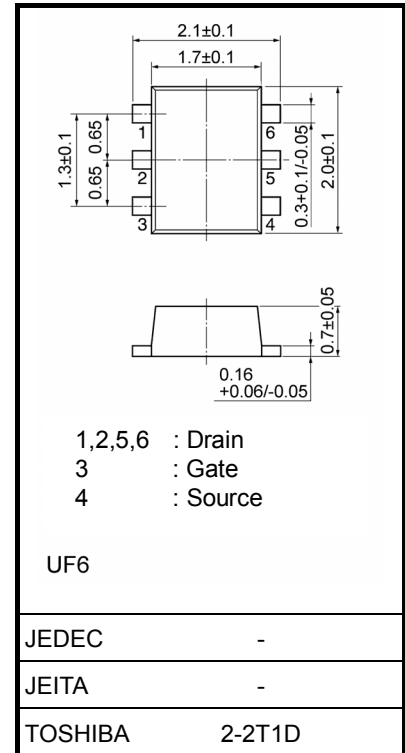
## Marking



## Equivalent Circuit



Unit: mm



Weight: 7 mg (typ.)

## Handling Precaution

When handling individual devices that are not yet mounted on a circuit board, be sure that the environment is protected against electrostatic discharge. Operators should wear anti-static clothing, and containers and other objects that come into direct contact with devices should be made of anti-static materials.

Start of commercial production  
2003-11

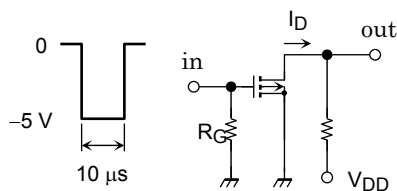
## Electrical Characteristics (Ta = 25°C)

| Characteristics                | Symbol        | Test Condition  | Min   | Typ. | Max      | Unit          |    |
|--------------------------------|---------------|---|---|------|----------|---------------|----|
| Gate leakage current           | $I_{GSS}$     | $V_{GS} = \pm 8 \text{ V}, V_{DS} = 0$                  | —   | —    | $\pm 10$ | $\mu\text{A}$ |    |
| Drain-Source breakdown voltage | $V_{(BR)DSS}$ | $I_D = -10 \text{ mA}, V_{GS} = 0$                      | -20   | —    | —        | V             |    |
|                                | $V_{(BR)DSX}$ | $I_D = -10 \text{ mA}, V_{GS} = +10 \text{ V}$          | -10   | —    | —        |               |    |
| Drain cut-off current          | $I_{DSS}$     | $V_{DS} = -20 \text{ V}, V_{GS} = 0$                    | —   | —    | -10      | $\mu\text{A}$ |    |
| Gate threshold voltage         | $V_{th}$      | $V_{DS} = -10 \text{ V}, I_D = -0.2 \text{ mA}$         | -0.5  | —    | -1.2     | V             |    |
| Forward transfer admittance    | $ Y_{fs} $    | $V_{DS} = -10 \text{ V}, I_D = -1.5 \text{ A}$ (Note2)  | 3.1   | 6.2  | —        | S             |    |
| Drain-Source on-resistance     | $R_{DS(ON)}$  | $I_D = -1.5 \text{ A}, V_{GS} = -4.5 \text{ V}$ (Note2) | —   | 49   | 64       | m $\Omega$    |    |
|                                |               | $I_D = -1.5 \text{ A}, V_{GS} = -2.5 \text{ V}$ (Note2) | —   | 73   | 100      |               |    |
|                                |               | $I_D = -1.5 \text{ A}, V_{GS} = -2.0 \text{ V}$ (Note2) | —   | 105  | 205      |               |    |
| Input capacitance              | $C_{iss}$     | $V_{DS} = -10 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$ | —   | 800  | —        | pF            |    |
| Reverse transfer capacitance   | $C_{rss}$     | $V_{DS} = -10 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$ | —   | 120  | —        | pF            |    |
| Output capacitance             | $C_{oss}$     | $V_{DS} = -10 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$ | —   | 160  | —        | pF            |    |
| Switching time                 | Turn-on time  | $t_{on}$  | $V_{DD} = -10 \text{ V}, I_D = -1.5 \text{ A},$         | —    | 15       | —             | ns |
|                                | Turn-off time | $t_{off}$   | $V_{GS} = 0 \text{ to } -5 \text{ V}, R_G = 4.7 \Omega$ | —    | 51       | —             |    |

Note2: Pulse test

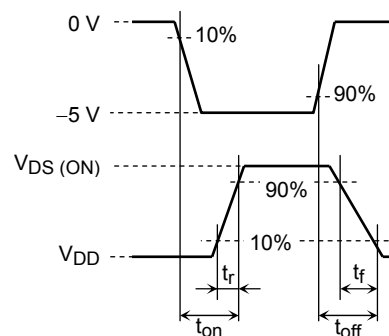
## Switching Time Test Circuit

### (a) Test Circuit

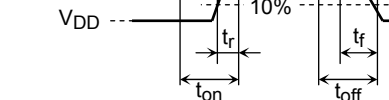


$V_{DD} = -10 \text{ V}$   
 $R_G = 4.7 \Omega$   
 Duty  $\leq 1\%$   
 $V_{IN}: t_r, t_f < 5 \text{ ns}$   
 Common Source  
 $T_a = 25^\circ\text{C}$

### (b) $V_{IN}$



### (c) $V_{OUT}$

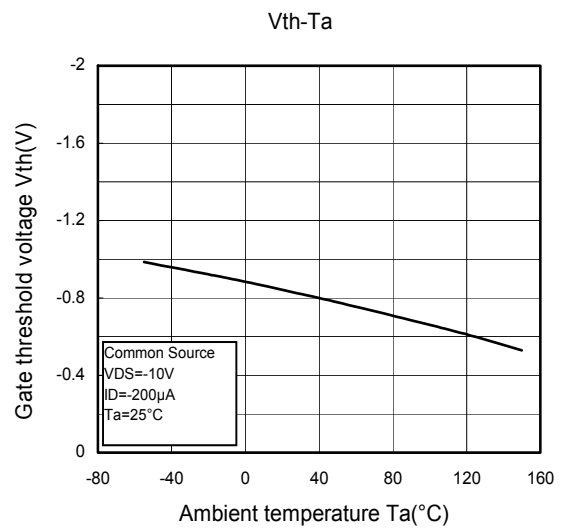
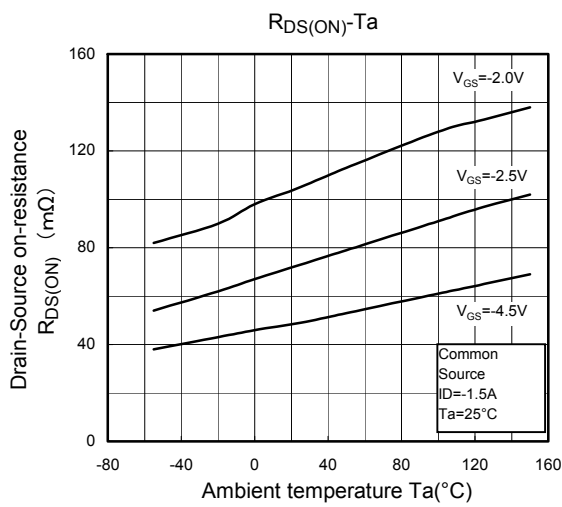
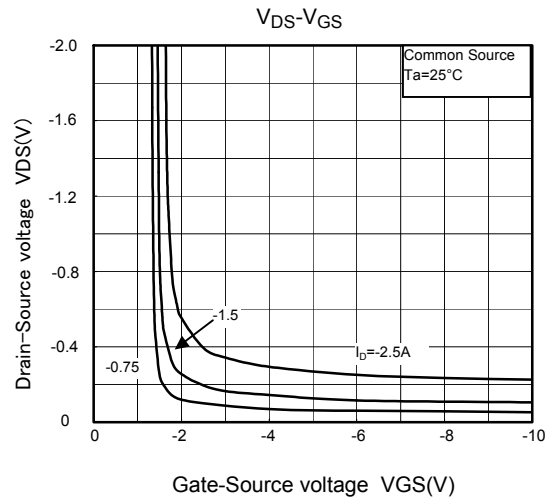
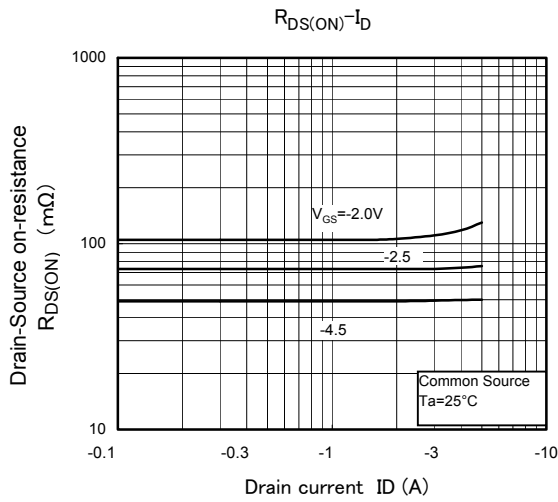
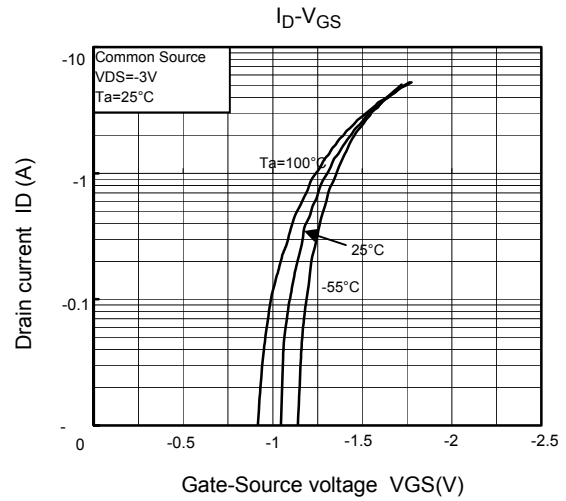
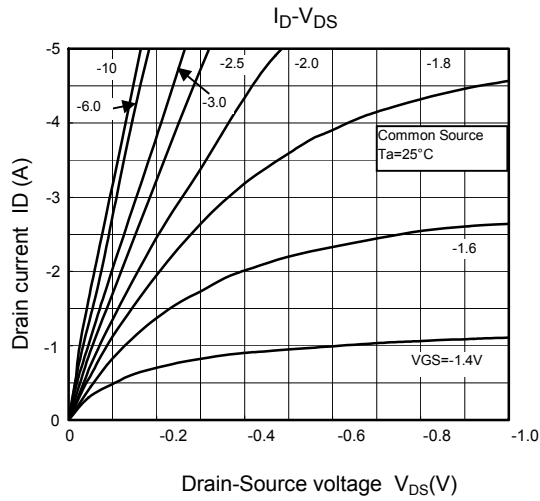


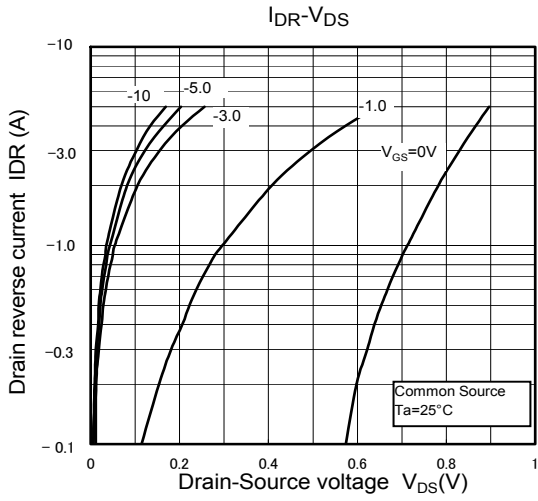
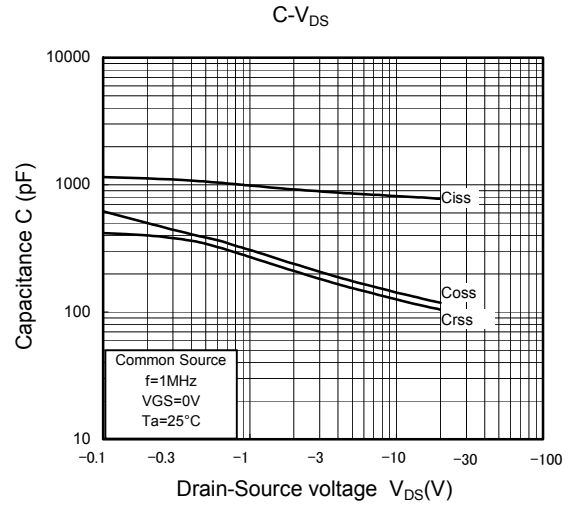
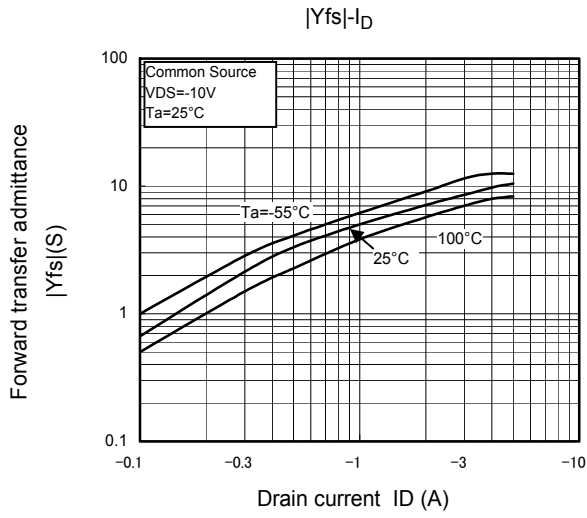
## Precaution

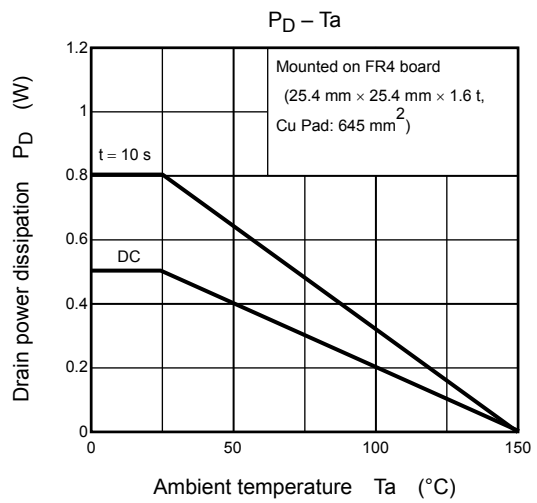
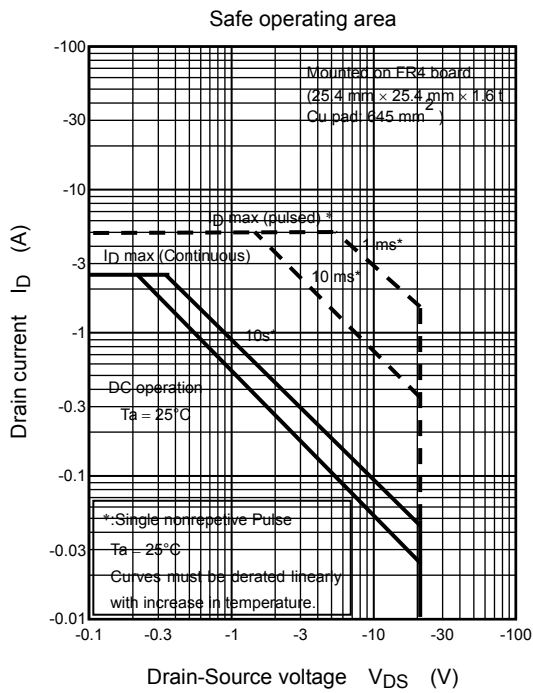
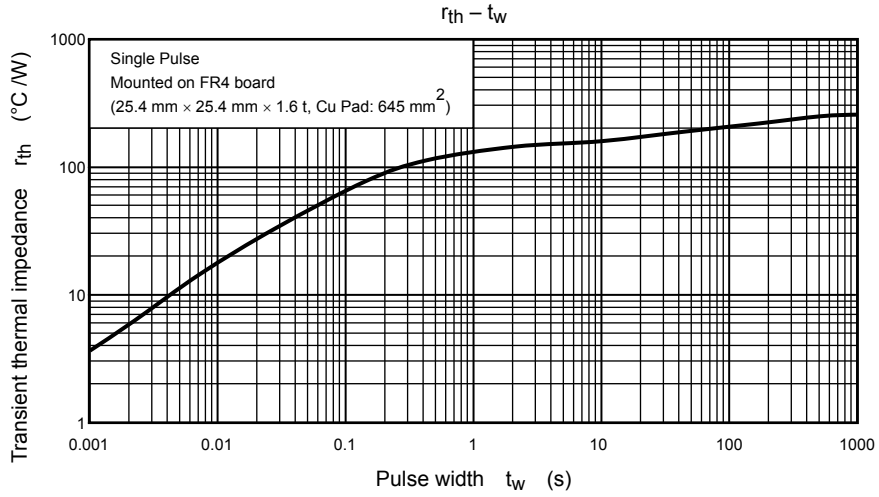
$V_{th}$  can be expressed as the voltage between gate and source when the low operating current value is  $I_D = -200 \mu\text{A}$  for this product. For normal switching operation,  $V_{GS(ON)}$  requires a higher voltage than  $V_{th}$  and  $V_{GS(OFF)}$  requires a lower voltage than  $V_{th}$ .

(The relationship can be established as follows:  $V_{GS(OFF)} < V_{th} < V_{GS(ON)}$ )

Be sure to take this into consideration when using the device.







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